



# N-Channel 30-V (D-S) Fast Switching MOSFET

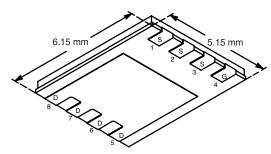
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
30	0.0075 at V <sub>GS</sub> = 10 V	19		
	0.010 at V <sub>GS</sub> = 4.5 V	17		

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET<sup>®</sup> Power MOSFET
- 100 % R<sub>g</sub> Tested
- Compliant to RoHS Directive 2002/95/EC



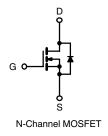




**Bottom View** 

Ordering Information: Si7446BDP-T1-E3 (Lead (Pb)-free)

Si7446BDP-T1-GE3 (Lead-(Pb)-free and Halogen-free)



Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		$V_{DS}$	30		٧
Gate-Source Voltage		$V_{GS}$	± 20		
Continuous Prain Current (T = 150°C)a	T <sub>A</sub> = 25°C	I <sub>D</sub>	19	12	۸
Continuous Drain Current (T <sub>J</sub> = 150°C) <sup>a</sup>	T <sub>A</sub> = 70°C		15	9	
Pulsed Drain Current		I <sub>DM</sub>	50		Α
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	4.0	1.6	
Marrian on Danier Discipation 8	T <sub>A</sub> = 25°C	P <sub>D</sub>	4.8	1.9	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70°C		3.0	1.2	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations (Peak Temperature	, and the second	260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum lunction to Ambienta	t ≤ 10 s	R <sub>thJA</sub>	21	26	 [	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		55	65	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	1.6	2.0		

#### Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<a href="www.vishay.com/ppg?73257">www.vishay.com/ppg?73257</a>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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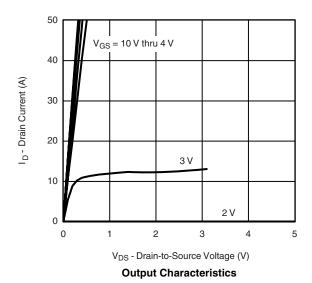
<b>MOSFET SPECIFICATIONS</b> $T_J = 25$ °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$			3.0	V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zava Cata Valtaga Dvain Current		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V	1		1	μΑ		
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$		5				
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α		
Drain-Source On-State Resistance <sup>a</sup>	D	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 19 A	0.0064 0.0		0.0075			
	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 17 \text{ A}$		0.0084	0.010	Ω		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 19 A		60		S		
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 4.0 A, V <sub>GS</sub> = 0 V		0.75	1.2	V		
Dynamic <sup>b</sup>								
Input Capacitance	C <sub>iss</sub>			3076				
Output Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		657		pF			
Reverse Transfer Capacitance	C <sub>rss</sub>			248				
Total Gate Charge	$Q_g$			22	33	nC		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 5.0 \text{ V}, I_{D} = 19 \text{ A}$		8.3				
Gate-Drain Charge	$Q_{gd}$			4.7		 		
Gate Resistance	$R_{g}$		0.4	0.8	1.2	Ω		
Turn-On Delay Time	t <sub>d(on)</sub>			20	30			
Rise Time	$\begin{array}{c} t_r \\ \\ t_{d(off)} \end{array} \hspace{0.2in} V_{DD} = 15 \text{ V, } R_L = 15 \Omega \\ I_D \cong 1 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 6 \Omega \end{array}$		16	25	ns			
Turn-Off Delay Time			120	180				
Fall Time	t <sub>f</sub>	-		43	65	110		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.3 A, dl/dt = 100 A/μs		40	80			

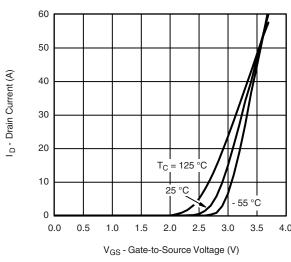
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





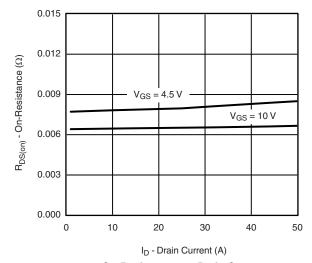
**Transfer Characteristics** 



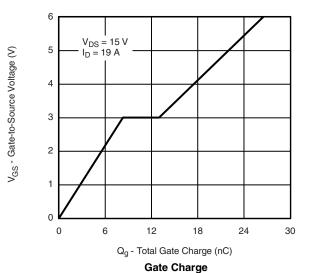


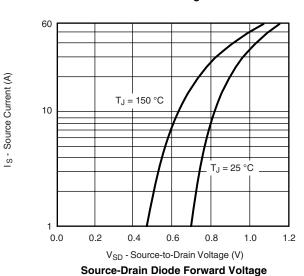


## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



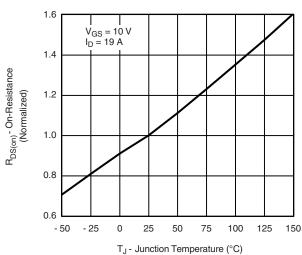
#### On-Resistance vs. Drain Current



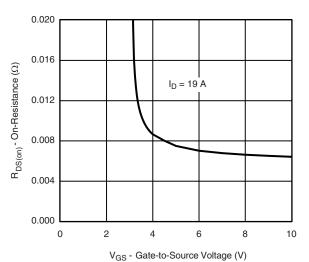


4000 Ciss 3200 C - Capacitance (pF) 2400 Coss 1600 800 0 12 4 8 16 20 0 V<sub>DS</sub> - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature

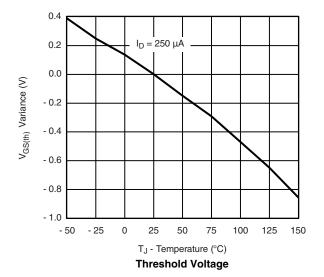


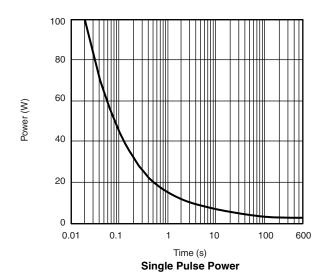
On-Resistance vs. Gate-to-Source Voltage

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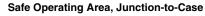
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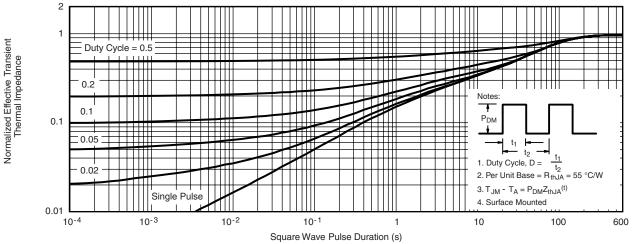
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





100 Limited by R<sub>DS(c</sub> 10 10 μs I<sub>D</sub> - Drain Current (A) 100 μs 1 ms 10 ms 100 ms 0.1 T<sub>C</sub> = 25 °C Single Pulse DC 0.01 0.1 V<sub>DS</sub> - Drain-to-Source Voltage (V) \*  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

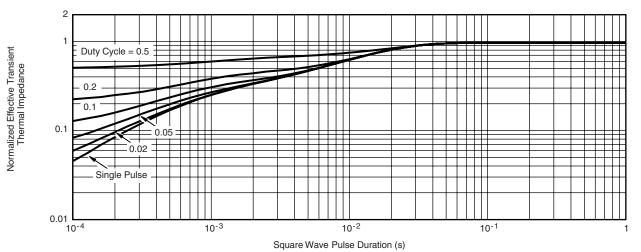




Normalized Thermal Transient Impedance, Junction-to-Ambient



# TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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